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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SJ624

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The 2SJ624 is a switching device which can be driven directly by a 1.8 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 1.8 V drive available
- · Low on-state resistance

RDS(on)1 = 54 m Ω MAX. (VGS = -4.5 V, ID = -2.5 A)

RDS(on)2 = 71 m Ω MAX. (VGS = -2.5 V, ID = -2.5 A)

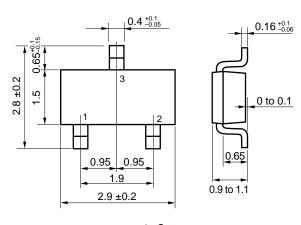
 $R_{DS(on)3} = 108 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = -1.8 \text{ V, Ip} = -1.5 \text{ A)}$

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ624	SC-96 (Mini Mold Thin Type)

Marking: XH

PACKAGE DRAWING (Unit: mm)



1 : Gate

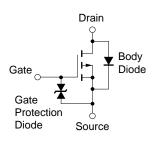
2 : Source

3: Drain

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-20	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓8.0	V
Drain Current (DC) (T _A = 25°C)	I _{D(DC)}	∓4.5	Α
Drain Current (pulse) Note1	D(pulse)	∓18	Α
Total Power Dissipation	P _{T1}	0.2	W
Total Power Dissipation Note2	P _{T2}	1.25	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

EQUIVALENT CIRCUIT



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Mounted on FR-4 board, $t \le 5$ sec.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

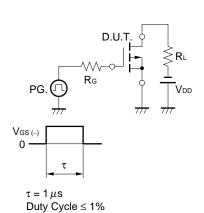
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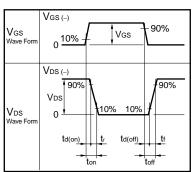


ELECTRICAL CHARACTERISTICS (TA = 25°C)

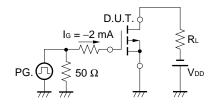
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	V _{DS} = -20 V, V _{GS} = 0 V			-10	μΑ
Gate Leakage Current	lgss	V _G S = ∓8.0 V, V _D S = 0 V			∓10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1.0 \text{ mA}$	-0.45	-0.75	-1.5	V
Forward Transfer Admittance	yfs	V _{DS} = -10 V, I _D = -2.5 A	5.0	9.5		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = -4.5 V, ID = -2.5 A		43	54	mΩ
	RDS(on)2	V _{GS} = -2.5 V, I _D = -2.5 A		53	71	mΩ
	RDS(on)3	Vgs = -1.8 V, ID = -1.5 A		65	108	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		813		pF
Output Capacitance	Coss	V _{GS} = 0 V		165		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		69		pF
Turn-on Delay Time	t d(on)	V _{DD} = -10 V, I _D = -2.5 A		14		ns
Rise Time	t r	V _{GS} = -4.0 V		42		ns
Turn-off Delay Time	td(off)	$R_G = 10 \Omega$		80		ns
Fall Time	t f			92		ns
Total Gate Charge	Q _G	V _{DD} = -16 V		8.1		nC
Gate to Source Charge	Qgs	V _{GS} = -4.0 V		1.3		nC
Gate to Drain Charge	Q _{GD}	I _D = -4.5 A		2.8		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 4.5 A, VGS = 0 V		0.90		V

TEST CIRCUIT 1 SWITCHING TIME

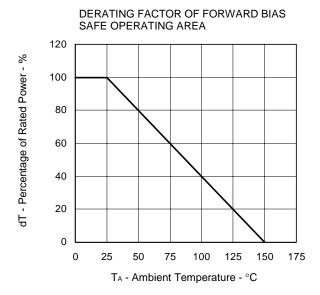


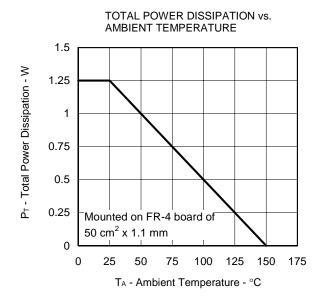


TEST CIRCUIT 2 GATE CHARGE

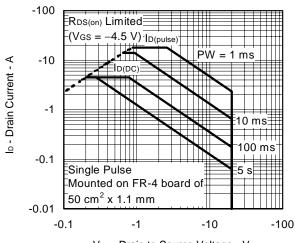


TYPICAL CHARACTERISTICS (TA = 25°C)



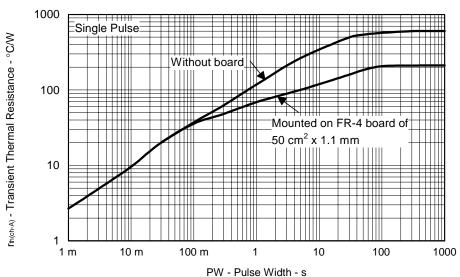


FORWARD BIAS SAFE OPERATING AREA

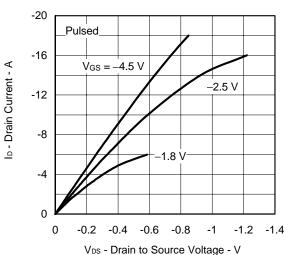


V_{DS} - Drain to Source Voltage - V

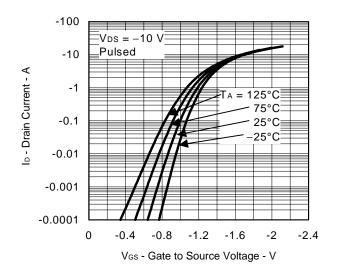
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



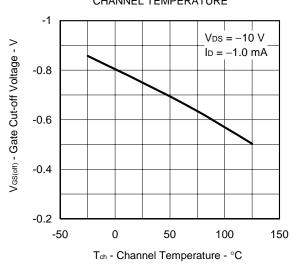
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



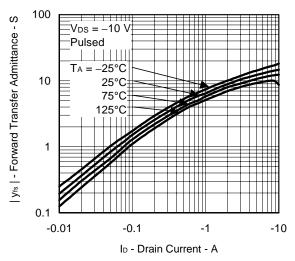
FORWARD TRANSFER CHARACTERISTICS



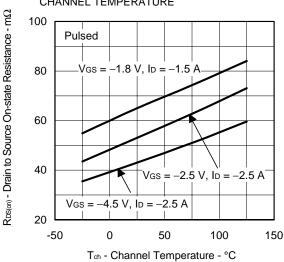
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



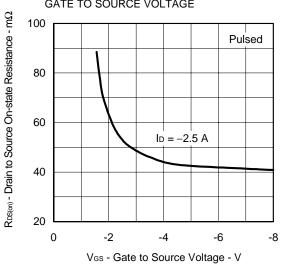
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



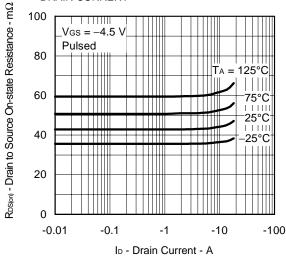
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



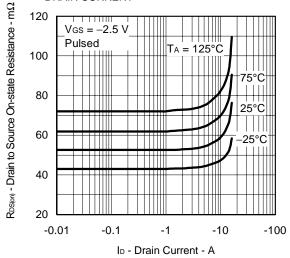
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



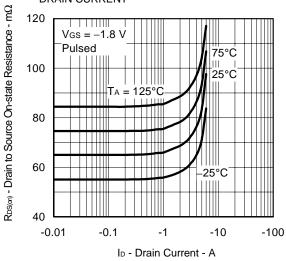
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



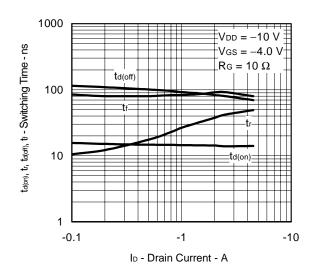
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



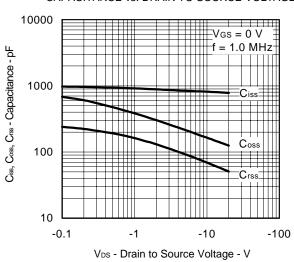
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



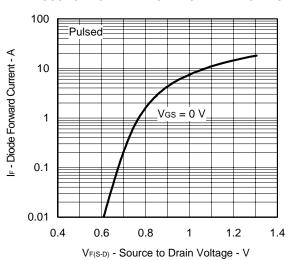
SWITCHING CHARACTERISTICS



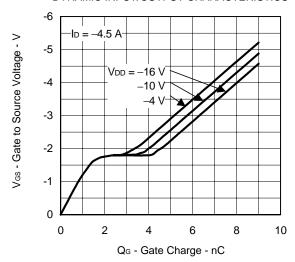
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



NEC 2SJ624

[MEMO]

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